

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
OFF CHARACTERISTICS (Note 5)						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-40	—	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-6	—	—	V	I _E = -50μA
Collector-Base Cutoff Current	I _{CBO}	—	—	-100	nA	V _{CB} = -40V, I _E = 0
		—	—	-50	μA	V _{CB} = -40V, I _E = 0, T _A = 150°C
Emitter-Base Cutoff Current	I _{EBO}	—	—	-100	nA	V _{EB} = -6V, I _C = 0
ON CHARACTERISTICS (Note 5)						
DC Current Gain	h _{FE}	220	—	—	—	V _{CE} = -1V, I _C = -0.5A
		200	—	400	—	V _{CE} = -1V, I _C = -1A
		100	—	—	—	V _{CE} = -1V, I _C = -3A
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	—	-150	—	I _C = -0.5A, I _B = -5mA
		—	—	-200	mV	I _C = -1A, I _B = -10mA
		—	—	-500	mV	I _C = -3A, I _B = -0.3A
Equivalent On-Resistance	R _{CE(SAT)}	—	—	167	mΩ	I _E = -3A, I _B = -0.3A
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	—	-1.0	V	I _C = -1A, I _B = -0.1A
Base-Emitter Turn-on Voltage	V _{BE(ON)}	—	—	-1.0	V	V _{CE} = -2V, I _C = -1A
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f _T	—	150	—	MHz	V _{CE} = -10V, I _C = -100mA, f = 100MHz
Output Capacitance	C _{obo}	—	35	—	pF	V _{CB} = -10V, f = 1MHz
Input Capacitance	C _{ibo}	—	150	—	pF	V _{CB} = -5V, f = 1MHz
SWITCHING CHARACTERISTICS						
Turn-On Time	t _{on}	—	53	—	ns	V _{CC} = -10V, I _C = -2A, I _{B1} = -200mA
Delay Time	t _d	—	12	—	ns	
Rise Time	t _r	—	41	—	ns	
Turn-Off Time	t _{off}	—	180	—	ns	V _{CC} = -10V, I _C = -2A, I _{B1} = I _{B2} = -200mA
Storage Time	t _s	—	146	—	ns	
Fall Time	t _f	—	34	—	ns	

Notes: 5. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.

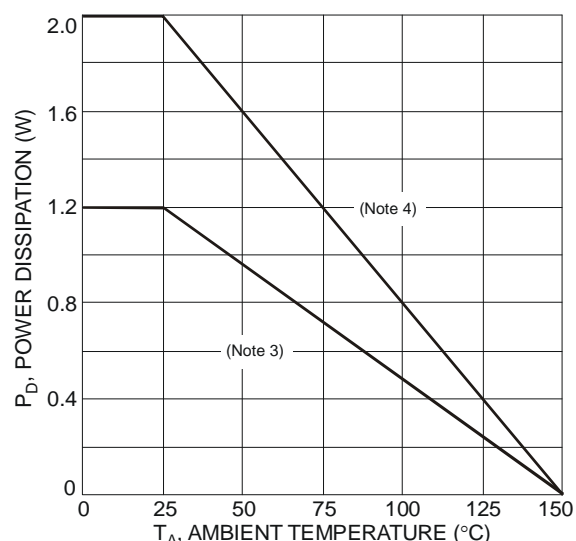


Fig. 1 Power Dissipation vs. Ambient Temperature

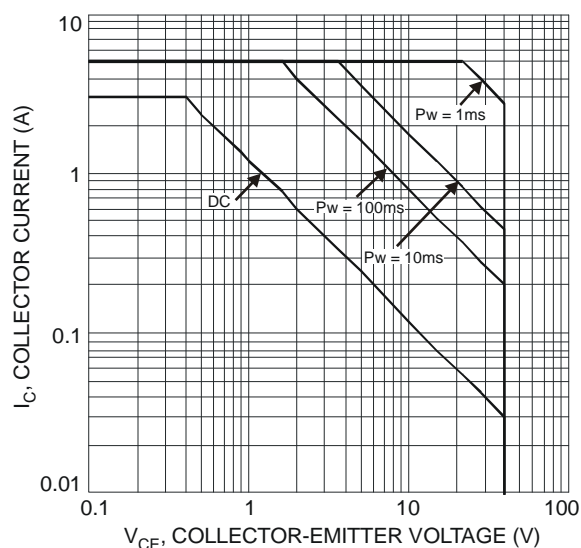


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage (Note 3)

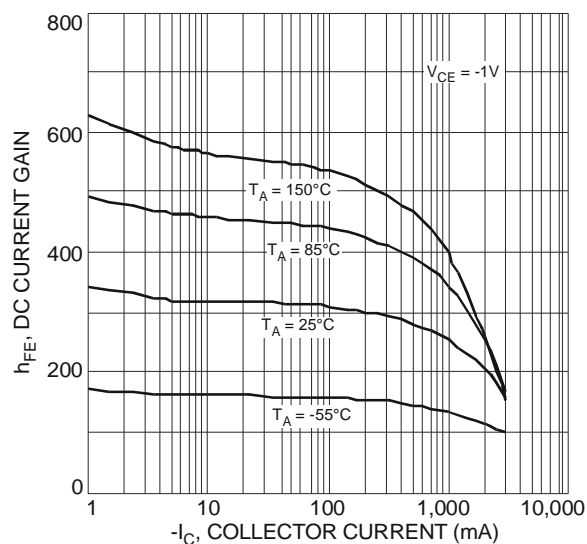


Fig. 3 Typical DC Current Gain vs. Collector Current

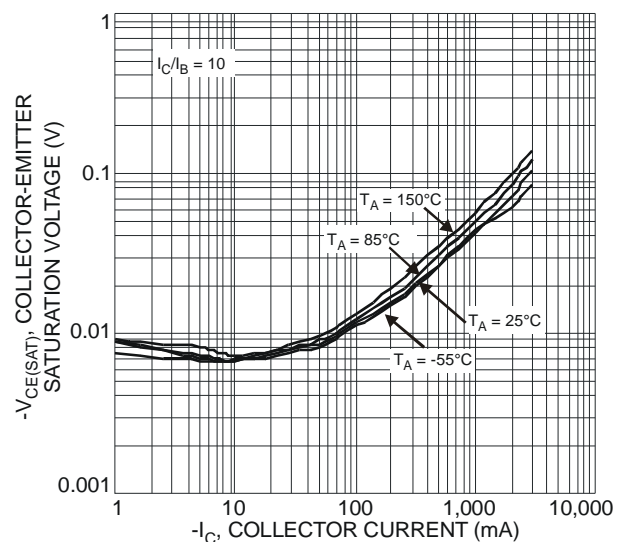


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

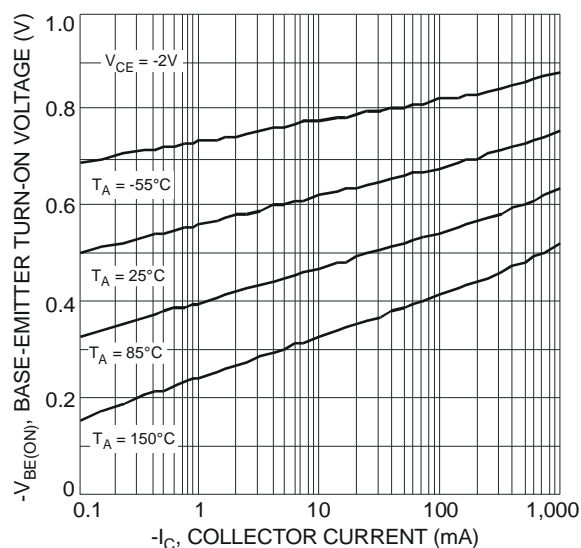


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

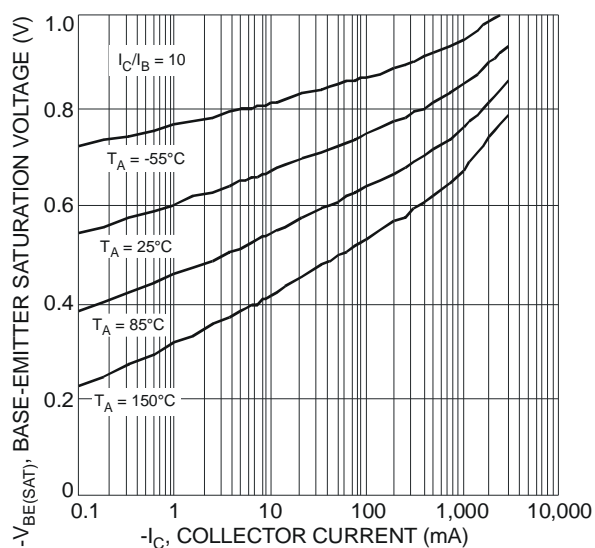


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

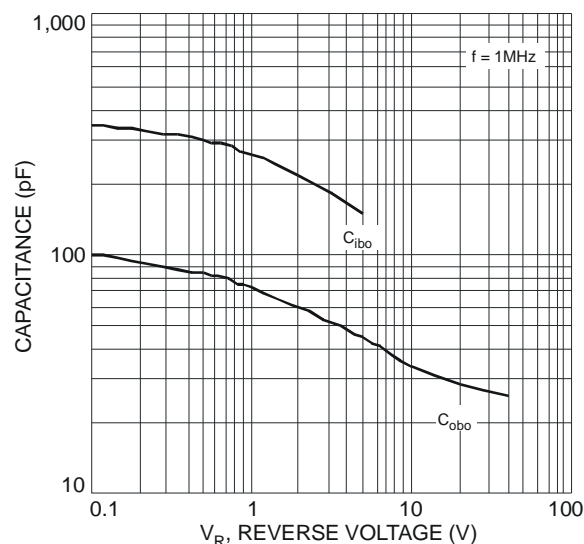


Fig. 7 Typical Capacitance Characteristics

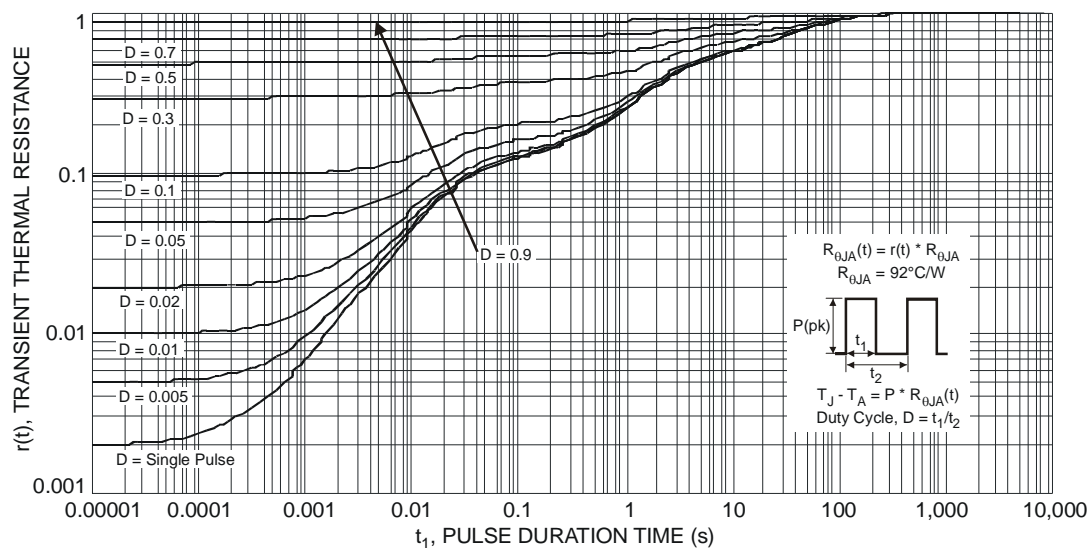


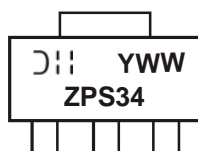
Fig. 8 Transient Thermal Response (Note 3)

Ordering Information (Note 6)

Part Number	Case	Packaging
DJT4030P-13	SOT-223	2500/Tape & Reel

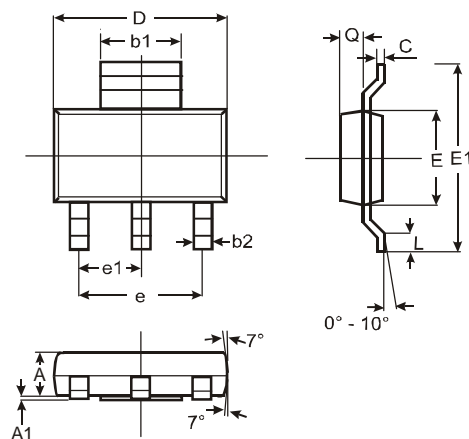
Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



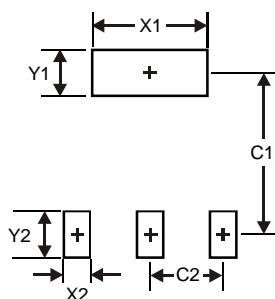
ZPS34 = Product Type Marking Code
 YWW = Date Code Marking
 Y = Last digit of year (ex: 8 = 2008)
 WW = Week code 01 - 52

Package Outline Dimensions



SOT-223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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